

INFRARED EMITTING DIODES

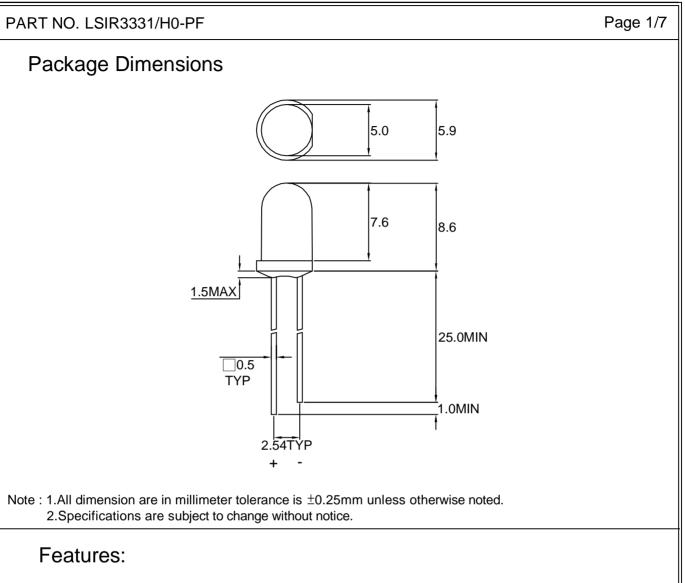


LSIR3331/H0-PF

DATA SHEET

- DOC. NO : QW0905-LSIR3331/H0-PF
- REV. : A
- DATE : 16 May.- 2006





- 1. High radiant intensity.
- 2. Suitable for pulsed applications.
- 3. Low average degradation.

Descriptions:

The LSIR3331/H0-PFseries are high power solution grown efficiency Gallium Arsenide infrared emitting diodes encapsulated in blue transparent plastic T-1 3/4 package individually

Device Selection Guide:

PART NO	MATERIAL	LENS COLOR	
LSIR3331/H0-PF	GaAIAs/GaAs	Blue Transparent	



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Absolute Maximum Ratings at Ta=25 $^\circ\!\mathbb{C}$				
Parameter	Symbol	Ratings	UNIT	
		SIR		
Power Dissipation	PD	100	mW	
Peak Forward Current (300PPS,10 μ s Pulse)	IFP	1	А	
Forward Current	lF	50	mA	
Reverse Voltage	Vr	5	V	
Electrostatic Discharge	ESD	2000	V	
Operating Temperature	Topr	-40 ~ +85	°C	
Storage Temperature	Tstg	-40 ~ +85	°C	

Electrical Optical Characteristics (Aa=25°C)

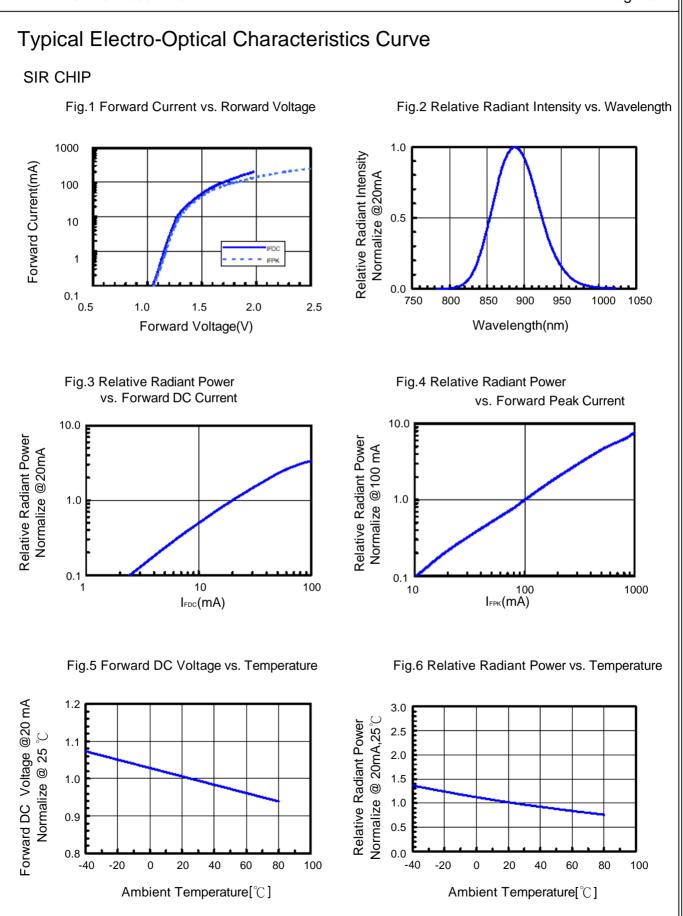
PARAMETER	SYMBOL	Min.	Тур.	Max.	UNIT	TEST CONDITION
Radiant Intensity	Le	5.0	9.0		mW/sr	IF=20mA
Aperture Radiant Incidence	Ee	0.7	1.3		mW/cm ²	IF=20mA
Peak Wavelength	λ peak		880		nm	IF=20mA
Spectral Line Half Width	$ riangle \lambda$		50		nm	IF=20mA
Forward Voltage	VF		1.4	1.7	V	IF=20mA
Reverse Current	IR			100	μ A	VR=5V
Viewing Angle	2 <i>θ</i> 1/2		40		deg	

Note : 1.The forward voltage data did not including $\pm 0.1V$ testing tolerance. 2. The radiant intensity data did not including $\pm 15\%$ testing tolerance.



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Storage time:

- 1.The operation of Temperatures and RH are : 5 $^\circ\!\mathrm{C}$ ~35 $^\circ\!\mathrm{C}$,RH<60%.
- 2.Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp proof box with descanting agent. Considering the tape life, we suggest our customers to use our products within a year(from production date).
- 3.If opened more than one week in an atmosphere 5 $^\circ C\,$ ~ 35 $^\circ C$,RH<60%, they should be treated at 60 $^\circ C\,\pm 5\,^\circ C$ fo r 15hrs.

Drive Method:

LED is a current operated device, and therefore, require some kind of current limiting incorporated into the driver circuit. This current limiting typically takes the form of a current limiting resistor placed in series with the LED.

Consider worst case voltage variations than could occur across the current limiting resistor. The forwrd current should not be allowed to change by more than 40% of its desired value.



(A) Recommended circuit.

(B) The difference of brightness between LED could be found due to the VF-IF characteristics of LED.

Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED.

ESD(Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing these LED. All devices, equipment and machinery must be properly grounded.

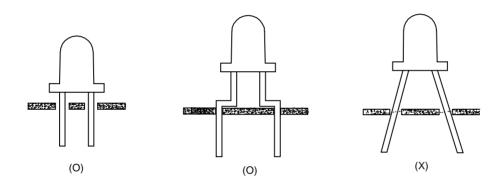


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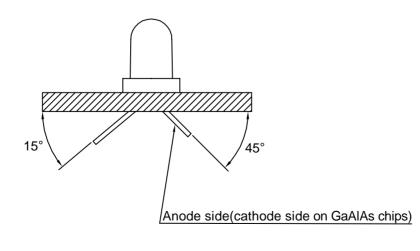
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Mounting:

1. If the leads are subjected to stress during soldering a printed circuit board, illumination failure may result immediately or later during use. For this reason, make sure that the intervals between the installation holes in the board are equal to the intervals between the leads (after forming if done) so that no stress is applied to the lead.



2. The LED lamps are designed for high-density mounting and have a structure which can alleviate mechanical stress due to clinching . Nevertheless, take care to avoid the occurrence of residual mechanical stress due to clinching.





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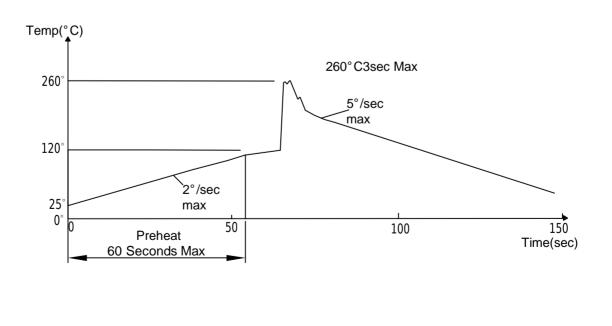
Soldering Condition(Pb-Free)

1.Iron:

Soldering Iron:30W Max Temperature 350°C Max Soldering Time:3 Seconds Max(One Time) Distance:2mm Min(From solder joint to body)

2. Wave Soldering Profile

Dip Soldering Preheat: 120°C Max Preheat time: 60seconds Max Ramp-up 2°C/sec(max) Ramp-Down:-5°C/sec(max) Solder Bath:260°C Max Dipping Time:3 seconds Max Distance:2mm Min(From solder joint to body)





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Reliability Test:

Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=20mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of detemining the resistance of a part in electrical and themal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=85 ℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40 °C ±5 °C 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65 ℃ ±5 ℃ 2.RH=90 %~95 % 3.t=240hrs ±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11
Thermal Shock Test	1.Ta=105 ℃±5℃&-40 ℃±5℃ (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011
Solder Resistance Test	1.T.Sol=260 ℃ ±5 ℃ 2.Dwell time= 10 ±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1
Solderability Test	1.T.Sol=230 ℃ ±5 ℃ 2.Dwell time=5 ±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2